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Electric-field control of single-molecule tautomerization†

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The electric field is an important parameter to vary in a single-molecule experiment, because it can directly affect the charge distribution around the molecule. Yet, performing such an experiment with a well-defined electric field for a model chemical reaction at an interface has proven to be extremely difficult. Here, by combining a graphene field-effect transistor and a gate-tunable scanning tunneling microscope (STM), we reveal how this strategy enables the intramolecular H atom transfer of a metal-free macrocycle to be controlled with an external field. Experiments and theory both elucidate how the energetic barrier to tautomerization decreases with increasing electric field. The consistency between the two results demonstrates the potential in using electric fields to engineer molecular switching mechanisms that are ubiquitous in nanoscale electronic devices.

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Introduction

Over the last 50 years there has been great interest in the influence of external electric fields on both molecular structure and chemical reactivity.^{1–9} Several enduring examples have firmly established that adsorption structures, vibrational frequencies and oxidation states are all affected by electric fields.^{10–14} Since electric fields alter the energies of molecular orbitals, they can also change activation barriers and the associated kinetic parameters for specific chemical reactions. This impact makes electric fields highly relevant to surface chemistry.^{3,6,7,9}

Recent advances in the synthesis, characterization and computational modeling of catalytic materials have inspired detailed predictions and verifications of electric field effects therein,^{5,8,9,15–17} but extant technical challenges still remain to be overcome.⁴ Unlike theoretical modelling, in an experiment it is not possible to set the surface electric field to any arbitrary value, nor always have a well-defined field. For instance, since the orientation and magnitude of the local electric field can vary significantly from one adsorption site to another on a

surface, its overall effect on catalytic activity can be challenging to predict. Furthermore, due to the complex morphology of catalytic surfaces and the lack of surface-sensitive experimental techniques specifically adapted to them, it is extremely difficult to characterize surface electric fields and their effect on chemical reactions.⁴ Fortunately, in both these aspects, STM contributes enormously due to its ability to apply oriented electric fields to adsorbed molecules and to detect the resulting effects at the atomic level. In particular, the sharp apex of an STM tip can sustain very high electric fields ($|E| \approx 1 \text{ V nm}^{-1}$) with low applied tip-substrate bias voltages ($|V_b| \approx 1 \text{ V}$). The ability to produce a high electric field in combination with precisely adjustable parameters makes STM-based methods ideal for testing the effects of electric fields on single-molecule reactions in a spatially resolved way.

Argonès *et al.* reported an STM characterization of an electric-field-induced Diels–Alder reaction, where a diene, covalently bonded to a gold tip, was brought into contact with a dienophile-covered substrate.¹⁷ The electric-field-induced chemical-bonding events were detectable by measuring the electric current. Alemani *et al.* noted similar effects that involved the isomerization of azobenzene under varying electric field conditions.¹⁸ Recently, STM tip induced electric field is shown to catalyze the *cis*-to-*trans* isomerization of cumulenes in solution.¹⁹

A drawback of STM for studying electric-field effects is the inseparability of its control parameters. Since only two of the three factors (tip-sample distance, bias voltage and tunneling current) can be varied independently, it is not easy to identify system responses that are directly attributable to electric-field effects alone. Here, we overcome this challenge by combining a

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graphene field-effect transistor with a gate-tunable STM. This combination enables an applied back-gate voltage to change the charge-carrier density on the graphene surface, which in turn varies the tip height in constant-current mode. In other words, the back-gating enables changing the tip-induced electric field without varying the set-point current and set-point voltage. Using this method, we observe the impact of the electric field on the tautomerization reaction of metal-free phthalocyanine (H_2Pc) deposited onto these back-gated graphene devices at a temperature of 5 K. We show that an increase of the absolute magnitude of the applied electric field leads to an increase in the reaction rate, which we attribute to a decrease in the activation barrier. The activation barrier is found to scale linearly with the applied electric field, which offers the possibility to control tautomerization reactions at the molecular level.

Methods

A. Experimental details

We used the back-gated graphene/ SiO_2 /Si device, shown schematically in Fig. 1. The graphene sample was grown *via* chemical-vapor deposition²⁰ and transferred on top of a heavily doped Si wafer coated with a 300 nm thick SiO_2 layer. The graphene was characterized with an optical microscope and Raman spectroscopy.²¹ Electrical contacts were made by depositing Cr (10 nm thick)/Au (30 nm thick) electrodes with a stencil mask. Free-base phthalocyanine molecules (Alfa Aesar) were evaporated onto the graphene in ultra-high vacuum at room temperature (298 K) using a Knudsen cell prior to cooling the sample to a temperature of 5 K. STM/STS measurements were performed with a home-built 5 K STM. It was equipped with electrochemically etched Pt-Ir tips bought from Agilent Technologies (N9801A), USA. The lock-in modulation for dI/dV measurements was 700 mV at a frequency of 425 Hz. We determined the reaction rate k by counting the number of switching events N_{switch} in every current-time trace and dividing it by the total measurement time t_{tot} , i.e., $k = N_{\text{switch}}/t_{\text{tot}}$.

B. Computational details

We investigated the influence of the electric field and charging on the activation barrier with the help of density functional theory (DFT). By using the nudged-elastic-band method²² implemented in Quantum Espresso,²³ we were able to find the minimum-energy path between two *trans* states. We used

the PBE functional²⁴ and ultrasoft pseudopotentials²⁵ with a 40 Ry cutoff for the wavefunctions and a 400 Ry cutoff for the charge density. The total energy was converged to a precision better than 5×10^{-5} Ha. For each calculation we used 15 nudged-elastic-band images and allowed for the geometrical optimization of each, including initial and final ones. To calculate the influence of the accumulated charge on the tautomerization reaction, we placed the H_2Pc on graphene. There, the simulated supercell was built from 8 by 8 graphene unit cells (128 carbon atoms in the graphene sheet). The lattice constant of the hexagonal supercell was 19.7 Å. The distance between the periodic images perpendicular to the graphene layer was 30 Å. In a second type of calculations we considered only the molecule in a cubic unit cell with a side length of 20 Å.

Results and discussion

In order to examine the influence of the electric field on the tautomerization reaction, an external voltage source was connected to the Si substrate so that back-gate voltages can be applied (Fig. 1) in an STM setting. This potential difference causes some charge accumulation at the Si/ SiO_2 interface, accompanied by an image charge on the graphene. This enables the back-gating to fill or deplete electronic states in the graphene, which shifts the Fermi energy with respect to the Dirac point. When measuring data with the STM in constant-current mode, the change in the density of states (DOS) of the graphene causes an adjustment in the tip-sample distance, which consequently modifies the tip-applied electric field (Fig. 1). The ability to disentangle the tip-sample distance, bias voltage and tunneling current is especially important for the study of many chemical reactions, because the activation of a particular reaction mechanism is strongly correlated with the number and the potential energy of the injected electrons used to trigger said mechanism.

The ability to control the external electric field without varying the set-point current and voltage was applied to investigate the electric-field effect on the hydrogen-transfer reaction of H_2Pc . H_2Pc is a planar π -conjugated molecule with D_{2h} symmetry. As shown in Fig. 2a, H_2Pc undergoes a tautomerization reaction in which two hydrogen atoms hop between four nitrogen atoms in the cavity, switching between two different *trans* conformations. The tautomerization in H_2Pc can be triggered by an STM-induced electronic excitation process at 5 K.^{26–29} According to DFT calculations (Fig. 2b), the highest occupied molecular orbitals (HOMOs) of both tautomers exhibit almost identical spatial shapes, and thus cannot be used to detect the position of the hydrogen atoms in the cavity or, in other words, to infer the state of the tautomerization of the molecule. The inset of Fig. 2c shows an STM image of H_2Pc taken at the molecule's HOMO resonance. Despite of a continuous change of the tautomerization state of the molecule during recording, the HOMO can be clearly recognized due to the theoretically predicted indistinguishability of the computed HOMOs. On the other hand, the lowest unoccupied molecular orbital (LUMO) has twofold symmetry (Fig. 2b). Thus, when we rotate the LUMO of one tautomer by 90°,



Fig. 1 Schematic of the method used to control the tip-induced electric field without varying the set-point current and voltage.





Fig. 2 (a) Ball-and-stick model of the intramolecular hydrogen transfer in the H₂Pc molecule. The hydrogen atoms, which are involved in the tautomerization, are highlighted in pink. (b) DFT calculations of the gas-phase H₂Pc HOMO (top) and LUMO (bottom). (c) STM topography of an H₂Pc monolayer at the LUMO resonance state ($I = 10$ pA, $V_b = 1.6$ V). Inset: The HOMO resonance state ($I = 10$ pA, $V_b = -2.1$ V). (d) A current signal recorded at the black dot in panel (c) ($I = 10$ pA, $V_b = 1.6$ V, $V_g = 0$ V).

it becomes equivalent to the LUMO of the other tautomer. The LUMO can hence be used to detect the position of hydrogen atoms inside the molecular cavity.

All the measurements were taken at a bias voltage of $V_b = 1.6$ V, which is high enough to induce the tautomerization but also low enough to ensure the stability of the tip during the measurements.²⁹ The tunnelling current was kept at 10 pA in all experiments. Since the tautomerization is faster than the STM scanning rate, when the H₂Pc molecules were imaged, the superposition of the LUMOs of the different tautomers appears as an octothorpe in the molecular cavity (Fig. 2c). Thus, the tautomeric state is still obscured even though the LUMOs of the two tautomers are in principle, distinguishable. Nevertheless, the change in the local density of states (LDOS) due to the tautomerization reaction can be easily detected in a current-time trace as a two-level telegraphic noise recorded at a fixed lateral position in constant-height mode. These fluctuations originate from the tautomerization itself, whose high- and low-conductance states can be assigned to the two tautomeric forms of H₂Pc.

Since the rate of the tautomerization reaction strongly depends on the position of the electron injection into the molecule,²⁶ we measured the switching rates at various positions over the H₂Pc molecule. To achieve a sufficiently low dispersion in the measured switching rate, we chose to perform them at an empirically determined location that maximizes the number of switching events (black dot in Fig. 2c). After the tip location was set in constant-current mode, the feedback loop was disabled to measure the reaction rate of the tautomerization by recording a current-time trace in constant-height mode (Fig. 2d and SI 1, ESI†).

Due to the spatial dependence of the switching rate, the molecules were rescanned following each measurement to verify that the tip remained at the predetermined position above the molecule. The reaction rate was then measured as a function of the applied gate voltage (V_g) (SI 2, ESI†), as shown in Fig. 3a. The experiment was then repeated for several different molecules. All these reaction rates were normalized with respect to their



Fig. 3 (a) Normalized reaction rate as a function of the applied gate voltage ($I = 10$ pA and $V_b = 1.6$ V). (b) Shift in the vertical tip position plotted as a function of the applied gate voltage. Inset: Differential conductance (dI/dV) measured on the bare graphene. (c) Normalized reaction rate as a function of electric field change (ΔE) due to the tip-sample distance change. In each panel, different colors represent measurements on different molecules. The reaction rates are normalized by dividing each value by the maximum reaction rate observed across all gate voltages for the same molecule.

maximum value to reduce the influence of any local surface corrugation or impurities that create “charge-puddles” below the molecules³⁰ and perturb the measured reaction rate (see SI 3, ESI†). The maximum reaction rate is attained when no gate voltage is applied ($V_g = 0$ V). We expect that the electric field applied between the tip and sample is around $E = 2.2$ V nm^{−1} at $V_g = 0$ V, based on the simple plate-capacitor model (see the discussion in SI 5, ESI†). The reaction rate decreases symmetrically with increasing $|V_g|$ (Fig. 3a). The reaction rate exhibits an inverse correlation with the tip-molecule distance (Fig. 3b and SI 4, ESI†).



Since sweeping the gate voltage is equivalent to shifting the Fermi energy with respect to the Dirac point, the changes in the tip height Δz as a function of the applied gate voltage are correlated with the DOS of the underlying graphene (inset in Fig. 3b). The modification of the electric field (ΔE) was derived from the change in the tip height (see the discussion in SI 5, ESI†). The correlation between the reaction rate and the changes in the electric field induced by the tip is clearly visible in Fig. 3c, where the reaction rate decreases when the tip-induced electric field is reduced. The gap in the electric-field spectrum at $-0.2 \text{ V nm}^{-1} < \Delta E < 0 \text{ V nm}^{-1}$ for $V_g < 0$ originates from a jump in the tip position around $V_g = 0 \text{ V}$ when sweeping towards negative gating values (see Fig. 3b).

To understand the role of the applied electric field on the reaction rate, we employed DFT calculations. The minimum-energy path (MEP) for hydrogen transfer in the molecule is shown in Fig. 4a. The DFT calculations predict that this transfer occurs through one of the *cis* states, regardless of whether the molecule is in the gas phase or on graphene. A direct transition that bypasses the *cis* state contributes negligibly due to its prohibitively high energy barrier (SI 6, ESI†). A transition complex between the *trans* and *cis* states exists with an intermediate-state energy E_{inter} that defines the activation energy E_a for the tautomerization reaction with respect to the initial energy E_{trans} , i.e., $E_a = E_{\text{inter}} - E_{\text{trans}}$. Using this definition, the calculated activation barrier is 487 meV ($11.23 \text{ kcal mol}^{-1}$). The activation barrier is lower than the value of previous report, 622 meV ($14.34 \text{ kcal mol}^{-1}$). The difference can be attributed to the differences in the *ab initio* approaches (SI 6, ESI†).

We studied the activation energy as a function of the magnitude of the electric field. The direction of the applied electric field is defined by the tilting angle α between the electric field and the normal vector of the molecule's plane (Fig. 4b). When the electric field is applied perpendicular to the molecule's plane ($\alpha = 0$), the energy variation due to electric field is negligible. However, considering the corrugation of the graphene surface, molecules generally experience an electric field from different tilting angles (Fig. 4c and SI 7, ESI†). As we increase α , the electric field effect on the activation barrier becomes increasingly pronounced (Fig. 4b and SI 8, ESI†). This calculated strong dependence on α explains the variation in the absolute value of the reaction rates across different molecules (Fig. S 3, ESI†). In addition, theory predicts that an applied electric field reduces the activation barrier. This is consistent with the experimental observations in Fig. 3c that the reaction rate drops as the electric field is reduced due to an increased tip height. In other words, an applied electric field of increasing magnitude reduces the activation barrier and increases the reaction rate.

To verify our conclusions, we also calculated the direct influence of accumulated charges on the hydrogen transfer. Our simulations predict that the activation barrier typically decreases as the absolute value of the accumulated charge increases at a constant electric field (SI 10, ESI†), which would correspond to an increase of the reaction rate with $|V_g|$. This is in contradiction to the experimental trends, and from this analysis we therefore conclude that the effect of accumulated charge alone cannot account for the observed change of reaction rate. Additionally, we examined



Fig. 4 (a) MEP calculations between the two *trans* states for the H₂Pc molecule in the gas phase without an applied electrical field. (b) Variation of the activation barrier with the electric field and the tilting angle, extracted from MEP calculations in the gas phase. The electric field is applied along the *z*-axis, and the molecular rotation takes place around an axis parallel to the *x*-direction, connecting two nitrogen atoms. (c) Two-dimensional and three-dimensional rendering of the STM topography of a H₂Pc monolayer on top of the graphene device.

molecular energy level shifts in relation to the applied gate voltage (SI 11, ESI†). This was done because the alignment of molecular levels with respect to the graphene substrate can be tuned through V_g , which in turn affects the number of injected electrons that activate the tautomerization reaction. The calculations show that the molecular energy levels shift monotonically when the applied back-gate voltage is increased from -40 V to $+40 \text{ V}$. Since the reaction rate decreases symmetrically around $V_g = 0 \text{ V}$ (see Fig. 3c), the energy level shift also cannot account for the changes of reaction rate observed in the experiment. To summarize, experimentally we observe the change of the tautomerization reaction rate as a function of gate voltage. By examining theoretically the roles of electric field, accumulated charge and molecular energy shifts that occur in the system, we find that the independent variable that best explains the functional



dependence is the electric field. We note that our theoretical modelling does not account for inhomogeneous distributions of the electric field or charge. We expect that such inhomogeneities due to the tip geometry or surface defects will lead to non-vanishing tilt angles α on the H₂Pc molecules and thus enhance the tilting effects of surface corrugation.

Conclusions

Tautomerization is an attractive mechanism to be used for controlling molecular switches because it is well-defined, reversible, intrinsic to the molecule, and does not involve any changes to the molecular frame. In particular, each of the different tautomeric states can be distinguished in conductance measurements.³¹ Finding a method of controlling the tautomerization reaction is central to enabling efficient molecular switching. Here, we have shown that the external electric field can be used to tune the tautomerization reaction in metal-free phthalocyanine molecules using a combination of a graphene field-effect transistor and a gate-tunable STM. By modulating the back-gate voltage, the electric field can be adjusted while keeping tunnelling current and applied bias voltage constant. Our results show that the tip-induced electric field reduces the activation barrier of the tautomerization reaction. Calculations demonstrate that the activation barrier is affected by the external electric field, especially when the tilting angle of the molecule is increased. Our work shows the value of using the electric field as a complementary control parameter in its own right, and represents a tangible step forward in the pursuit of integrated molecular electronics.

Author contributions

S. M., S. J. J. and K. K. designed the research. The gate-tunable graphene FETs were prepared by S. M. and K. P. with help of R. U. and P. P. Measurements were performed and analysed by S. M., K. P. and S. J. J. with help of C. D. The theoretical modelling and simulation was done by M. S., D. L. and F. P. The manuscript was drafted by S. M. and S. J. J. All authors participated in the writing and review of the final draft. All authors have given approval to the final version of the manuscript.

Conflicts of interest

There are no conflicts to declare.

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